

BOTTOM VIEW

# 2N7002BKM

60 V, 450 mA N-channel Trench MOSFET

Rev. 1 — 25 October 2010

Product data sheet

## 1. Product profile

### 1.1 General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small SOT883 (SC-101) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 1.2 Features and benefits

- Logic-level compatible
- Very fast switching
- Trench MOSFET technology
- ESD protection up to 2 kV
- AEC-Q101 qualified

### 1.3 Applications

- Relay driver
- High-speed line driver
- Low-side loadswitch
- Switching circuits

### 1.4 Quick reference data

Table 1. Quick reference data

| Symbol       | Parameter                        | Conditions  | Min   | Typ | Max | Unit     |
|--------------|----------------------------------|---|-------|-----|-----|----------|
| $V_{DS}$     | drain-source voltage             | $T_{amb} = 25\text{ °C}$  | -     | -   | 60  | V        |
| $V_{GS}$     | gate-source voltage              | $T_{amb} = 25\text{ °C}$  | -     | -   | ±20 | V        |
| $I_D$        | drain current                    | $T_{amb} = 25\text{ °C};$<br>$V_{GS} = 10\text{ V}$                       | [1] - | -   | 450 | mA       |
| $R_{DS(on)}$ | drain-source on-state resistance | $T_j = 25\text{ °C};$<br>$V_{GS} = 10\text{ V};$<br>$I_D = 500\text{ mA}$ | [2] - | 1   | 1.6 | $\Omega$ |

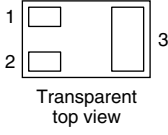
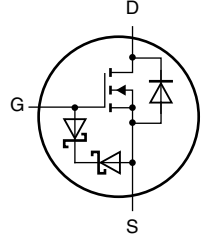
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.

[2] Pulse test:  $t_p \leq 300\text{ }\mu\text{s}; \delta \leq 0.01$ .



## 2. Pinning information

Table 2. Pinning

| Pin | Symbol | Description | Simplified outline  | Graphic symbol   |
|-----|--------|-------------|---|--|
| 1   | G      | gate        |  <p>Transparent top view</p> |  <p>017aaa000</p> |
| 2   | S      | source      |   |  |
| 3   | D      | drain       |   |  |

## 3. Ordering information

Table 3. Ordering information

| Type number | Package |   |         |
|-------------|---------|---|---------|
|             | Name    | Description   | Version |
| 2N7002BKM   | SC-101  | leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm | SOT883  |

## 4. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| 2N7002BKM   | Z8           |

## 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

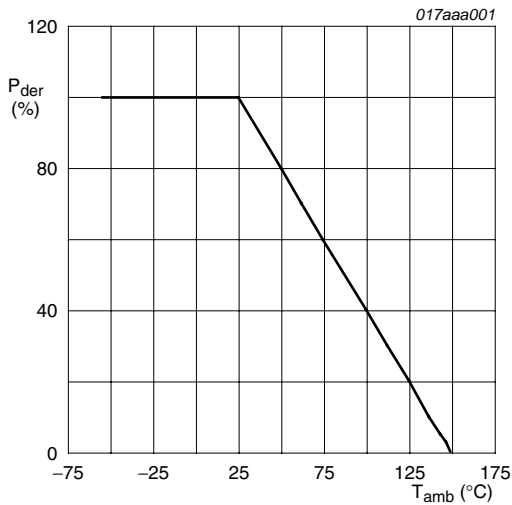
| Symbol   | Parameter            | Conditions   | Min | Max | Unit |
|----------|----------------------|--|-----|-----|------|
| $V_{DS}$ | drain-source voltage | $T_{amb} = 25\text{ °C}$   | -   | 60  | V    |
| $V_{GS}$ | gate-source voltage  | $T_{amb} = 25\text{ °C}$   | -   | ±20 | V    |
| $I_D$    | drain current        | $V_{GS} = 10\text{ V}$   | [1] |     |      |
|          |                      | $T_{amb} = 25\text{ °C}$   | -   | 450 | mA   |
|          |                      | $T_{amb} = 100\text{ °C}$  | -   | 220 | mA   |
| $I_{DM}$ | peak drain current   | $T_{amb} = 25\text{ °C}$ ;<br>single pulse; $t_p \leq 10\text{ }\mu\text{s}$ | -   | 1.2 | A    |

**Table 5. Limiting values ...continued**

In accordance with the Absolute Maximum Rating System (IEC 60134).

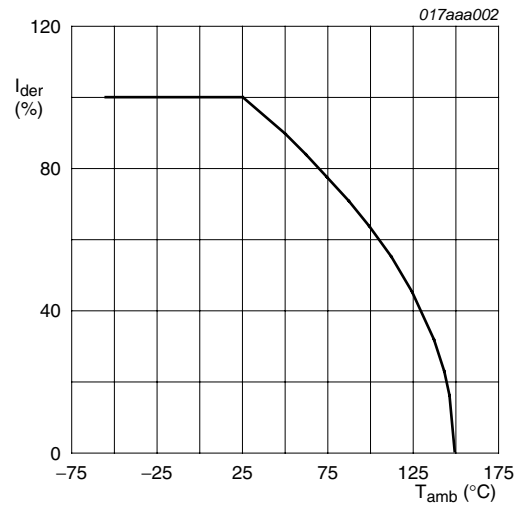
| Symbol                    | Parameter                       | Conditions               | Min | Max  | Unit |    |
|---------------------------|---------------------------------|--------------------------|-----|------|------|----|
| P <sub>tot</sub>          | total power dissipation         | T <sub>amb</sub> = 25 °C | [2] | -    | 360  | mW |
|                           |                                 |                          | [1] | -    | 715  | mW |
|                           |                                 | T <sub>sp</sub> = 25 °C  | -   | 2700 | mW   |    |
| T <sub>j</sub>            | junction temperature            |                          |     | 150  | °C   |    |
| T <sub>amb</sub>          | ambient temperature             |                          | -55 | +150 | °C   |    |
| T <sub>stg</sub>          | storage temperature             |                          | -65 | +150 | °C   |    |
| <b>Source-drain diode</b> |                                 |                          |     |      |      |    |
| I <sub>S</sub>            | source current                  | T <sub>amb</sub> = 25 °C | [1] | -    | 450  | mA |
| <b>ESD maximum rating</b> |                                 |                          |     |      |      |    |
| V <sub>ESD</sub>          | electrostatic discharge voltage | human body model         | [3] | -    | 2000 | V  |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Measured between all pins.



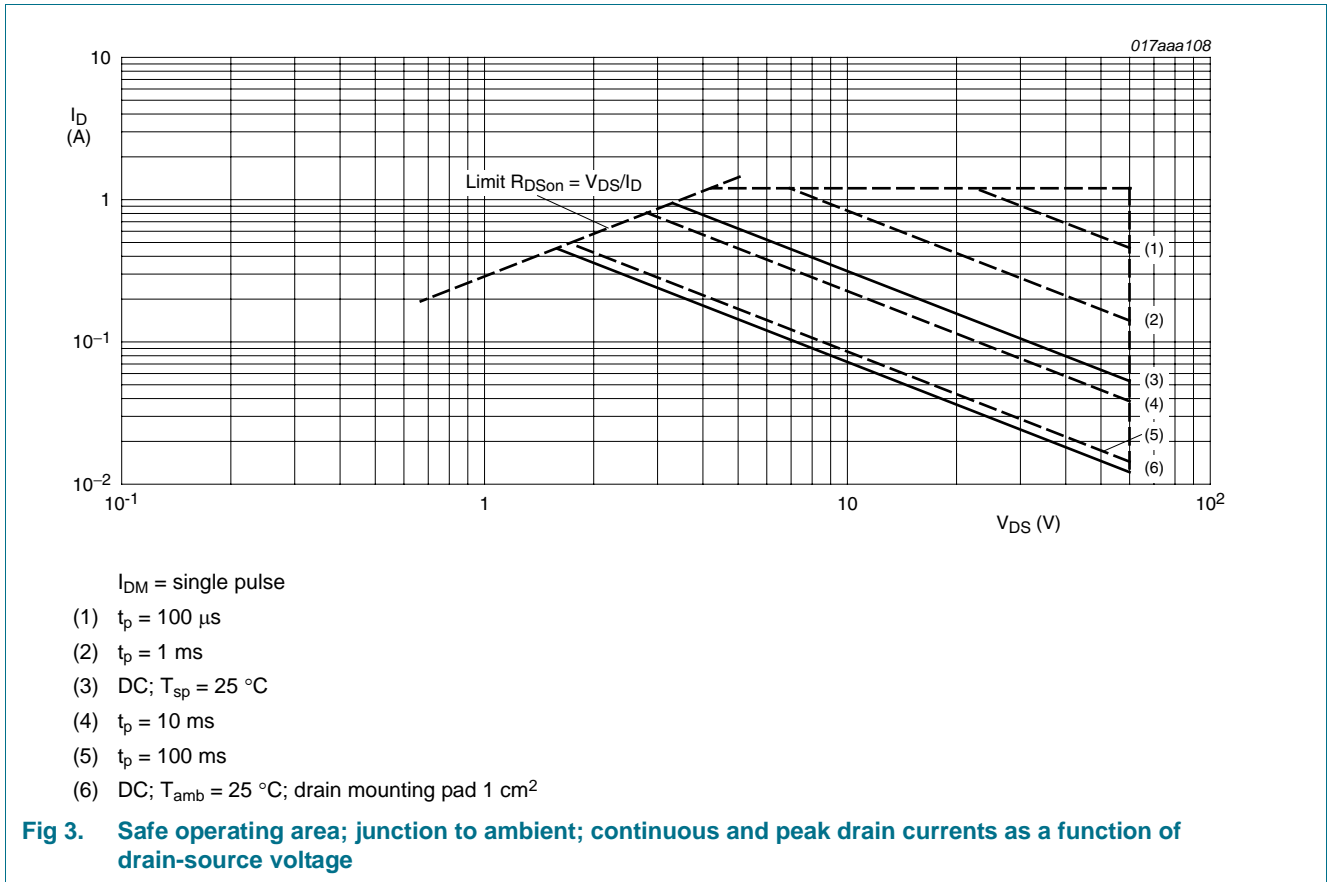
$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

**Fig 1. Normalized total power dissipation as a function of ambient temperature**



$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100\%$$

**Fig 2. Normalized continuous drain current as a function of ambient temperature**



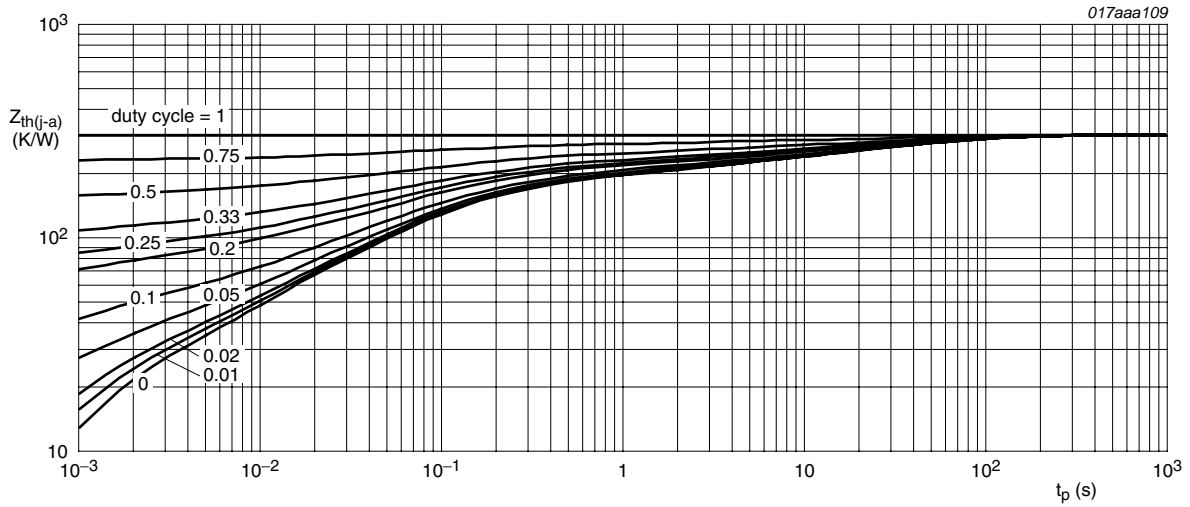
## 6. Thermal characteristics

**Table 6. Thermal characteristics**

| Symbol         | Parameter  | Conditions  | Min | Typ | Max | Unit |     |
|----------------|--|-------------|-----|-----|-----|------|-----|
| $R_{th(j-a)}$  | thermal resistance from junction to ambient      | in free air | [1] | -   | 305 | 350  | K/W |
|                |  |             | [2] | -   | 150 | 175  | K/W |
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point |             | -   | -   | 40  | K/W  |     |

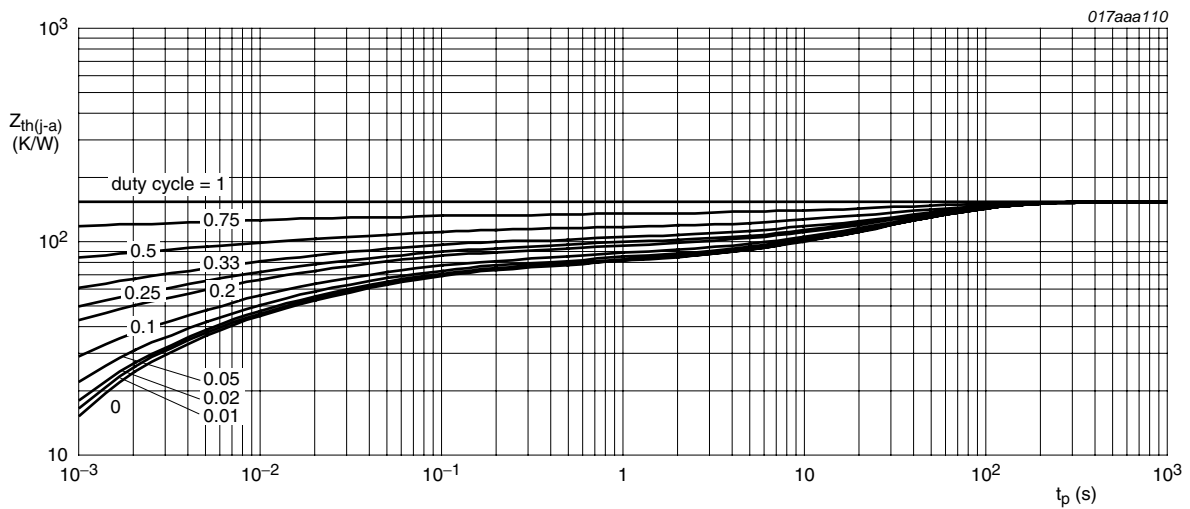
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain  $1 \text{ cm}^2$ .



FR4 PCB, standard footprint

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 1 cm<sup>2</sup>

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

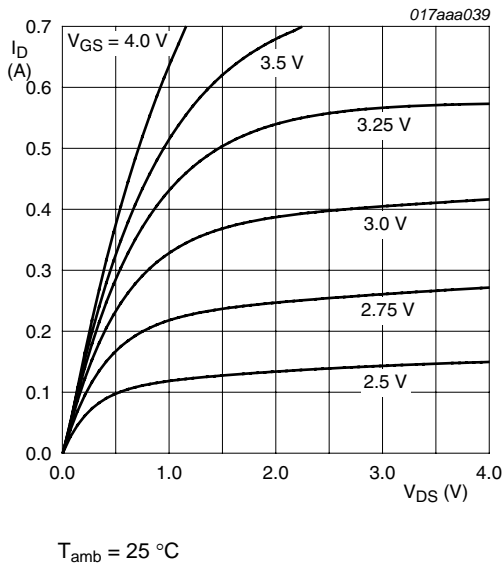
## 7. Characteristics

**Table 7. Characteristics**

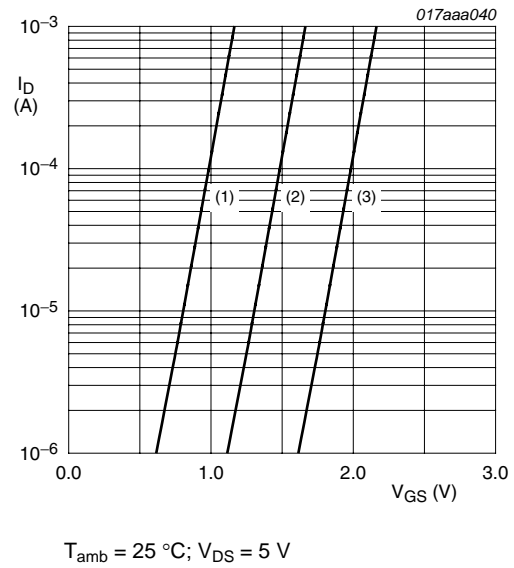
$T_j = 25\text{ °C}$  unless otherwise specified.

| Symbol                         | Parameter                        | Conditions  | Min  | Typ  | Max | Unit          |
|--------------------------------|----------------------------------|---|------|------|-----|---------------|
| <b>Static characteristics</b>  |                                  |   |      |      |     |               |
| $V_{(BR)DSS}$                  | drain-source breakdown voltage   | $I_D = 10\ \mu\text{A}; V_{GS} = 0\ \text{V}$   | 60   | -    | -   | V             |
| $V_{GS(th)}$                   | gate-source threshold voltage    | $I_D = 250\ \mu\text{A}; V_{DS} = V_{GS}$   | 1.1  | 1.6  | 2.1 | V             |
| $I_{DSS}$                      | drain leakage current            | $V_{DS} = 60\ \text{V}; V_{GS} = 0\ \text{V}$   |      |      |     |               |
|                                |                                  | $T_j = 25\text{ °C}$  | -    | -    | 1   | $\mu\text{A}$ |
|                                |                                  | $T_j = 150\text{ °C}$   | -    | -    | 10  | $\mu\text{A}$ |
| $I_{GSS}$                      | gate leakage current             | $V_{GS} = \pm 20\ \text{V}; V_{DS} = 0\ \text{V}$   | -    | -    | 10  | $\mu\text{A}$ |
| $R_{DS(on)}$                   | drain-source on-state resistance |   | [1]  |      |     |               |
|                                |                                  | $V_{GS} = 5\ \text{V}; I_D = 50\ \text{mA}$   | -    | 1.3  | 2   | $\Omega$      |
|                                |                                  | $V_{GS} = 10\ \text{V}; I_D = 500\ \text{mA}$   | -    | 1    | 1.6 | $\Omega$      |
| $g_{fs}$                       | forward transconductance         | $V_{DS} = 10\ \text{V}; I_D = 200\ \text{mA}$   | [1]  | -    | 550 | mS            |
| <b>Dynamic characteristics</b> |                                  |   |      |      |     |               |
| $Q_{G(tot)}$                   | total gate charge                | $I_D = 300\ \text{mA};$<br>$V_{DS} = 30\ \text{V};$<br>$V_{GS} = 4.5\ \text{V}$                   | -    | 0.5  | 0.6 | nC            |
| $Q_{GS}$                       | gate-source charge               |   | -    | 0.2  | -   | nC            |
| $Q_{GD}$                       | gate-drain charge                |   | -    | 0.1  | -   | nC            |
| $C_{iss}$                      | input capacitance                | $V_{GS} = 0\ \text{V}; V_{DS} = 10\ \text{V};$<br>$f = 1\ \text{MHz}$                             | -    | 33   | 50  | pF            |
| $C_{oss}$                      | output capacitance               |   | -    | 7    | -   | pF            |
| $C_{rss}$                      | reverse transfer capacitance     |   | -    | 4    | -   | pF            |
| $t_{d(on)}$                    | turn-on delay time               | $V_{DS} = 50\ \text{V};$<br>$R_L = 250\ \Omega;$<br>$V_{GS} = 10\ \text{V};$<br>$R_G = 6\ \Omega$ | -    | 5    | 10  | ns            |
| $t_r$                          | rise time                        |   | -    | 6    | -   | ns            |
| $t_{d(off)}$                   | turn-off delay time              |   | -    | 12   | 24  | ns            |
| $t_f$                          | fall time                        |   | -    | 7    | -   | ns            |
| <b>Source-drain diode</b>      |                                  |   |      |      |     |               |
| $V_{SD}$                       | source-drain voltage             | $I_S = 115\ \text{mA}; V_{GS} = 0\ \text{V}$  | 0.47 | 0.75 | 1.1 | V             |

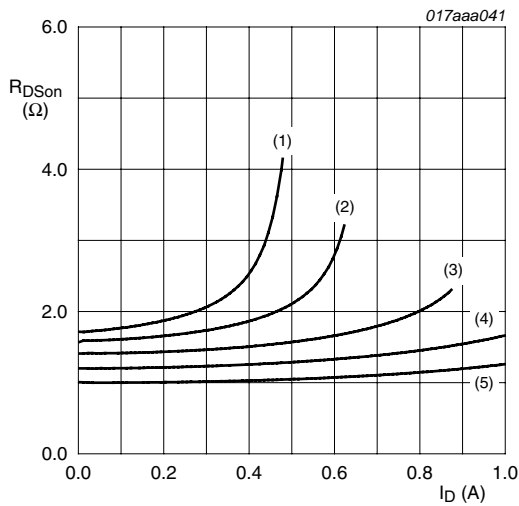
[1] Pulse test:  $t_p \leq 300\ \mu\text{s}; \delta \leq 0.01$ .



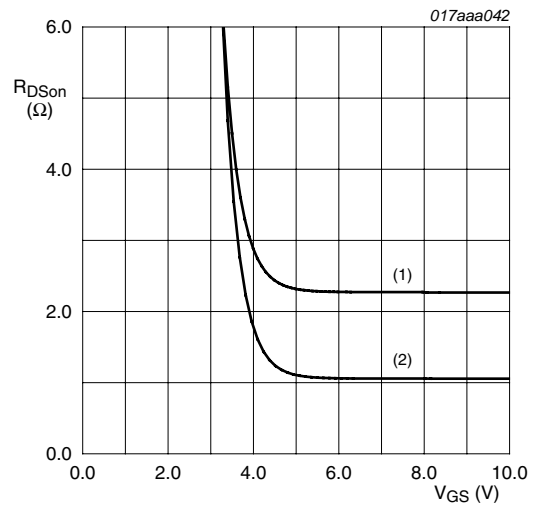
**Fig 6. Output characteristics: drain current as a function of drain-source voltage; typical values**



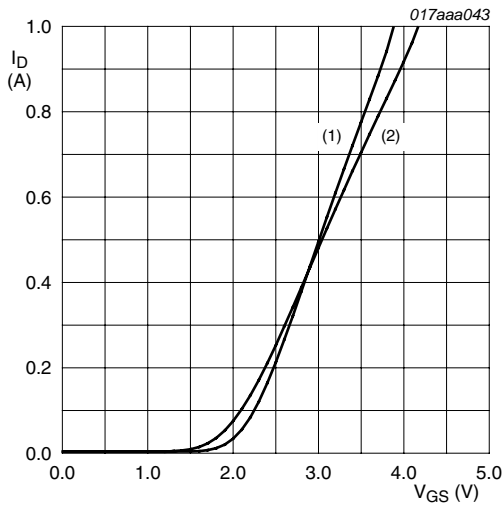
**Fig 7. Sub-threshold drain current as a function of gate-source voltage**



**Fig 8. Drain-source on-state resistance as a function of drain current; typical values**

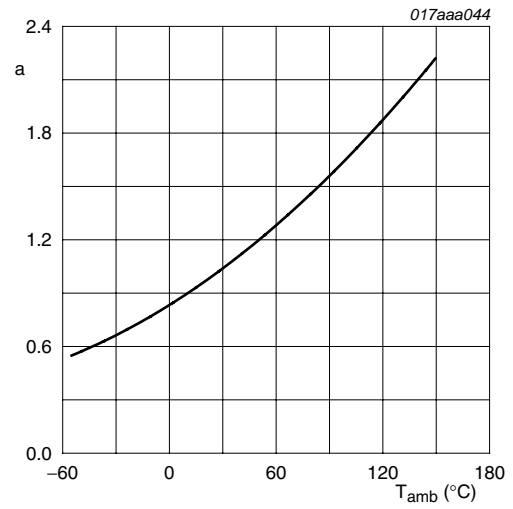


**Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values**



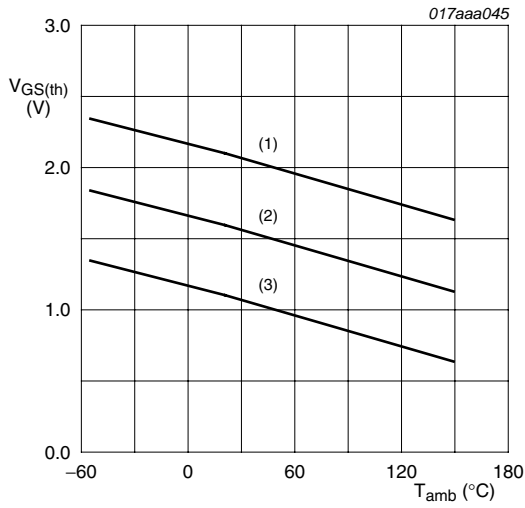
$V_{DS} > I_D \times R_{DS(on)}$   
 (1)  $T_{amb} = 25\text{ °C}$   
 (2)  $T_{amb} = 150\text{ °C}$

**Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values**



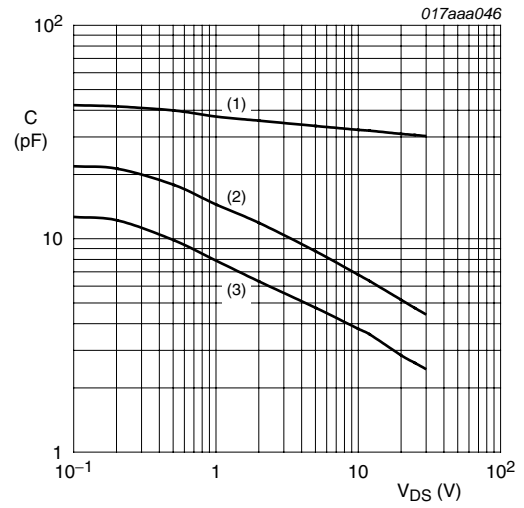
$$a = \frac{R_{DS(on)}}{R_{DS(on)(25^\circ C)}}$$

**Fig 11. Normalized drain-source on-state resistance as a function of ambient temperature; typical values**



$I_D = 0.25\text{ mA}; V_{DS} = V_{GS}$   
 (1) maximum values  
 (2) typical values  
 (3) minimum values

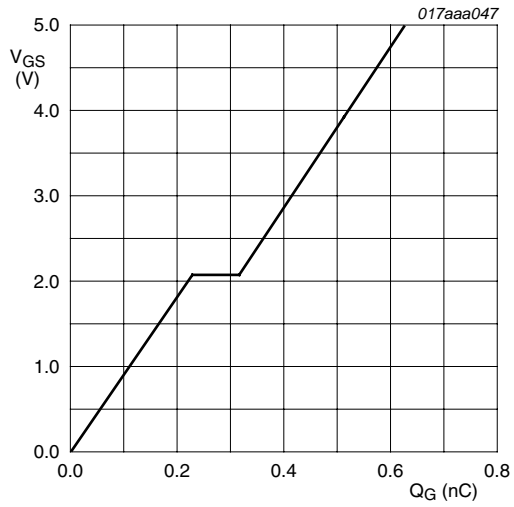
**Fig 12. Gate-source threshold voltage as a function of ambient temperature**



$f = 1\text{ MHz}; V_{GS} = 0\text{ V}$   
 (1)  $C_{iss}$   
 (2)  $C_{oss}$   
 (3)  $C_{rss}$

**Fig 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values**



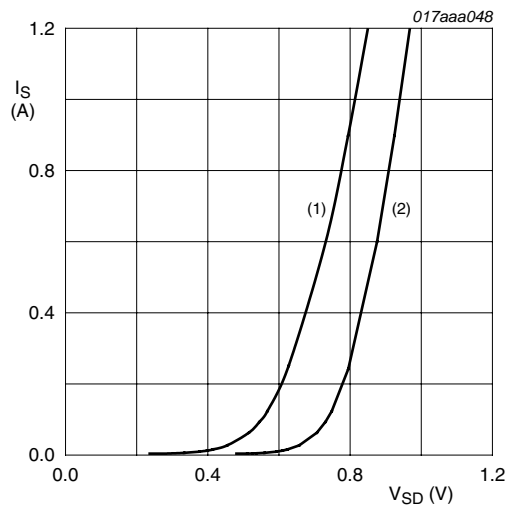


$I_D = 300 \text{ mA}; V_{DS} = 6 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig 14. Gate-source voltage as a function of gate charge; typical values**



**Fig 15. Gate charge waveform definitions**

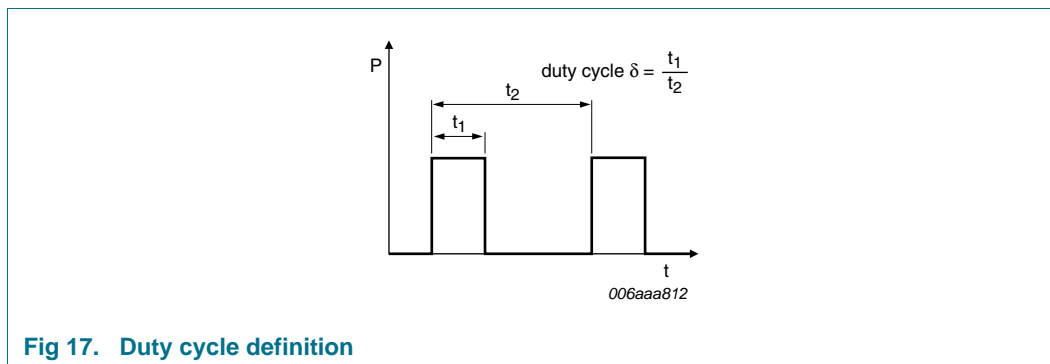


$V_{GS} = 0 \text{ V}$

- (1)  $T_{amb} = 150 \text{ }^\circ\text{C}$
- (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig 16. Source current as a function of source-drain voltage; typical values**

## 8. Test information



### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

9. Package outline

Leadless ultra small plastic package; 3 solder lands; body 1.0 x 0.6 x 0.5 mm

SOT883

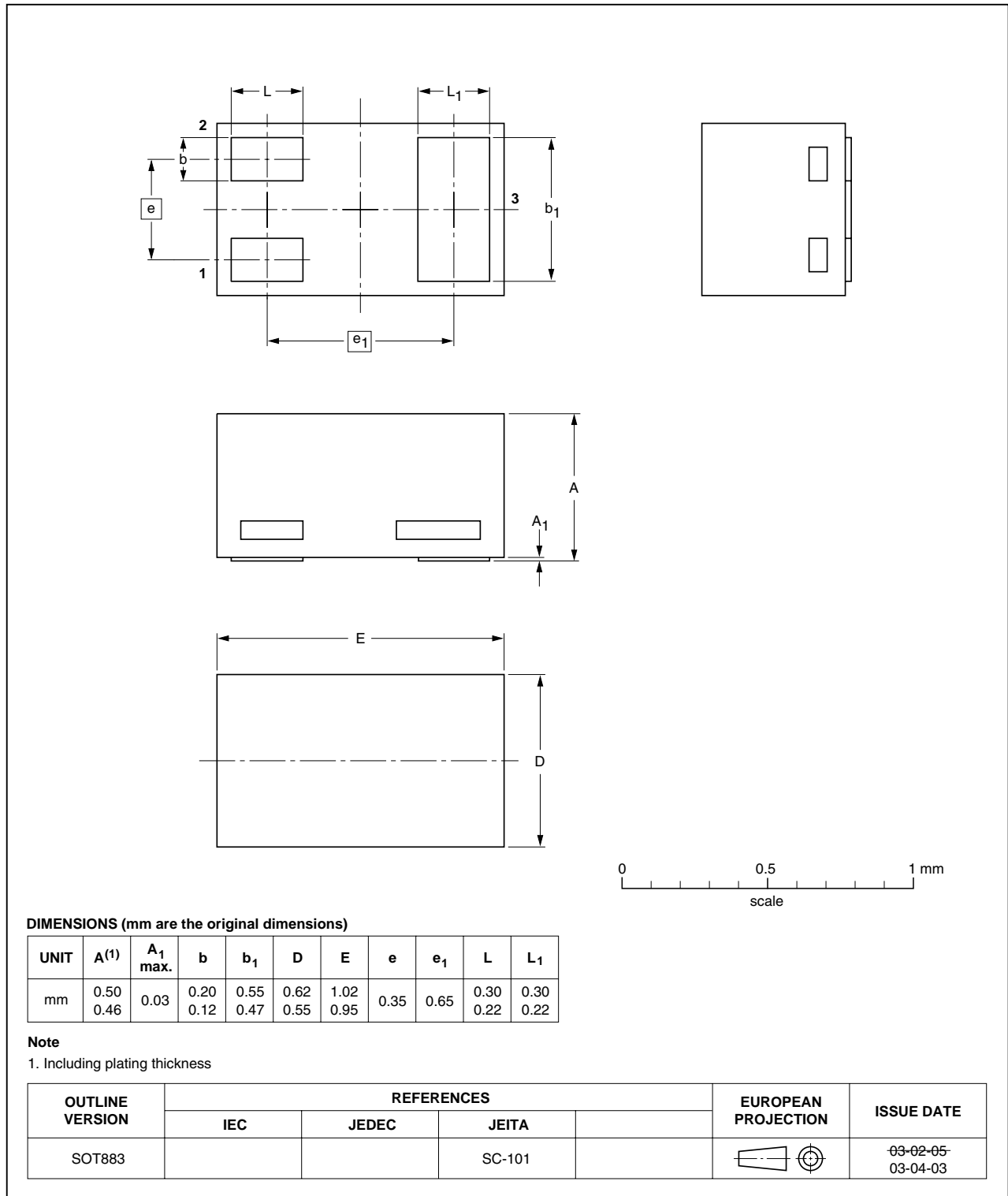
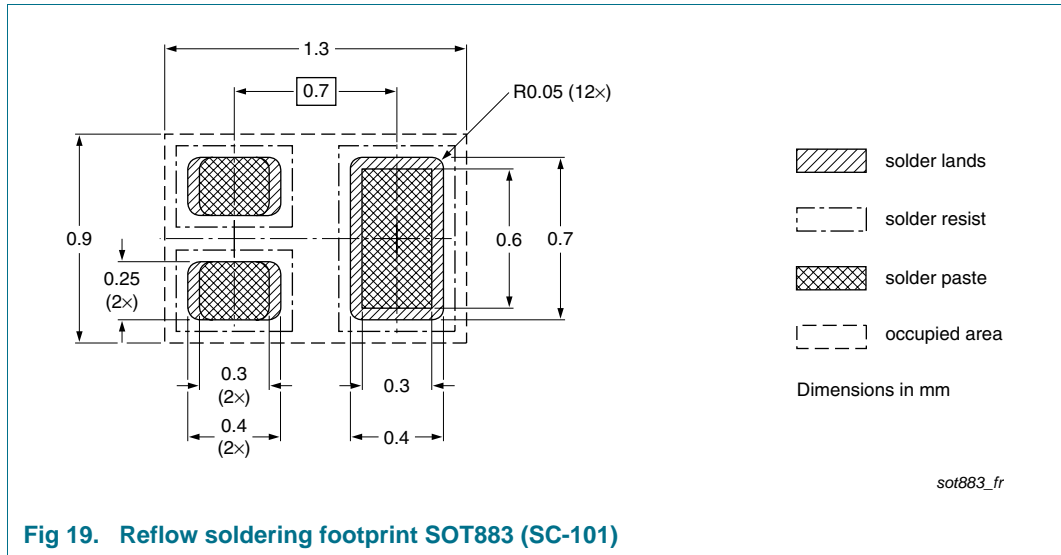


Fig 18. Package outline SOT883 (SC-101)

10. Soldering



## 11. Revision history

Table 8. Revision history

| Document ID   | Release date | Data sheet status  | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| 2N7002BKM v.1 | 20101025     | Product data sheet | -             | -          |

## 12. Legal information

### 12.1 Data sheet status

| Document status <sup>[1][2]</sup> | Product status <sup>[3]</sup> | Definition  |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet      | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet    | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet        | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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